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Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Active
Core Processor	R8C
Core Size	16-Bit
Speed	20MHz
Connectivity	I ² C, LINbus, SIO, SSU, UART/USART
Peripherals	POR, PWM, Voltage Detect, WDT
Number of I/O	75
Program Memory Size	48KB (48K x 8)
Program Memory Type	FLASH
EEPROM Size	4K x 8
RAM Size	4K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 5.5V
Data Converters	A/D 20x10b; D/A 2x8b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	80-LQFP
Supplier Device Package	80-LQFP (12x12)
Purchase URL	https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f21387cdfp-30

1.1.2 Specifications

Tables 1.1 and 1.2 outline the Specifications for R8C/38C Group.

Table 1.1 Specifications for R8C/38C Group (1)

Item	Function	Specification
CPU	Central processing unit	R8C CPU core <ul style="list-style-type: none">• Number of fundamental instructions: 89• Minimum instruction execution time: 50 ns (f(XIN) = 20 MHz, VCC = 2.7 to 5.5 V) 200 ns (f(XIN) = 5 MHz, VCC = 1.8 to 5.5 V)• Multiplier: 16 bits × 16 bits → 32 bits• Multiply-accumulate instruction: 16 bits × 16 bits + 32 bits → 32 bits• Operation mode: Single-chip mode (address space: 1 Mbyte)
Memory	ROM, RAM, Data flash	Refer to Table 1.3 Product List for R8C/38C Group
Power Supply Voltage Detection	Voltage detection circuit	<ul style="list-style-type: none">• Power-on reset• Voltage detection 3 (detection level of voltage detection 0 and voltage detection 1 selectable)
I/O Ports	Programmable I/O ports	<ul style="list-style-type: none">• Input-only: 1 pin• CMOS I/O ports: 75, selectable pull-up resistor• High current drive ports: 75
Clock	Clock generation circuits	<ul style="list-style-type: none">• 4 circuits: XIN clock oscillation circuit, XCIN clock oscillation circuit (32 kHz), High-speed on-chip oscillator (with frequency adjustment function), Low-speed on-chip oscillator• Oscillation stop detection: XIN clock oscillation stop detection function• Frequency divider circuit: Dividing selectable 1, 2, 4, 8, and 16• Low power consumption modes: Standard operating mode (high-speed clock, low-speed clock, high-speed on-chip oscillator, low-speed on-chip oscillator), wait mode, stop mode
		Real-time clock (timer RE)
Interrupts		<ul style="list-style-type: none">• Interrupt Vectors: 69• External: 9 sources ($\overline{\text{INT}} \times 5$, key input × 4)• Priority levels: 7 levels
Watchdog Timer		<ul style="list-style-type: none">• 14 bits × 1 (with prescaler)• Reset start selectable• Low-speed on-chip oscillator for watchdog timer selectable
DTC (Data Transfer Controller)		<ul style="list-style-type: none">• 1 channel• Activation sources: 39• Transfer modes: 2 (normal mode, repeat mode)
Timer	Timer RA	8 bits × 1 (with 8-bit prescaler) Timer mode (period timer), pulse output mode (output level inverted every period), event counter mode, pulse width measurement mode, pulse period measurement mode
	Timer RB	8 bits × 1 (with 8-bit prescaler) Timer mode (period timer), programmable waveform generation mode (PWM output), programmable one-shot generation mode, programmable wait one-shot generation mode
	Timer RC	16 bits × 1 (with 4 capture/compare registers) Timer mode (input capture function, output compare function), PWM mode (output 3 pins), PWM2 mode (PWM output pin)
	Timer RD	16 bits × 2 (with 4 capture/compare registers) Timer mode (input capture function, output compare function), PWM mode (output 6 pins), reset synchronous PWM mode (output three-phase waveforms (6 pins), sawtooth wave modulation), complementary PWM mode (output three-phase waveforms (6 pins), triangular wave modulation), PWM3 mode (PWM output 2 pins with fixed period)

Table 1.2 Specifications for R8C/38C Group (2)

Item	Function	Specification
Timer	Timer RE	8 bits × 1 Real-time clock mode (count seconds, minutes, hours, days of week), output compare mode
	Timer RF	16 bits × 1 Input capture mode (input capture circuit), output compare mode (output compare circuit)
	Timer RG	16 bits × 1 (with 2 capture/compare registers) Timer mode (input capture function, output compare function), PWM mode (output 1 pin), phase counting mode (available automatic measurement for the counts of 2-phase encoder)
Serial Interface	UART0, UART1	Clock synchronous serial I/O/UART × 2 channel
	UART2	Clock synchronous serial I/O, UART, I ² C mode (I ² C bus), multiprocessor communication function
Synchronous Serial Communication Unit (SSU)		1 (shared with I ² C bus)
I ² C bus		1 (shared with SSU)
LIN Module		Hardware LIN: 1 (timer RA, UART0)
A/D Converter		10-bit resolution × 20 channels, includes sample and hold function, with sweep mode
D/A Converter		8-bit resolution × 2 circuits
Comparator B		2 circuits
Flash Memory		<ul style="list-style-type: none"> • Programming and erasure voltage: VCC = 2.7 to 5.5 V • Programming and erasure endurance: 10,000 times (data flash) 1,000 times (program ROM) • Program security: ROM code protect, ID code check • Debug functions: On-chip debug, on-board flash rewrite function • Background operation (BGO) function (data flash)
Operating Frequency/Supply Voltage		f(XIN) = 20 MHz (VCC = 2.7 to 5.5 V) f(XIN) = 5 MHz (VCC = 1.8 to 5.5 V)
Current consumption		Typ. 7.0 mA (VCC = 5.0 V, f(XIN) = 20 MHz) Typ. 3.5 mA (VCC = 3.0 V, f(XIN) = 10 MHz) Typ. 4.0 μA (VCC = 3.0 V, wait mode (f(XCIN) = 32 kHz)) Typ. 2.0 μA (VCC = 3.0 V, stop mode)
Operating Ambient Temperature		−20 to 85°C (N version) −40 to 85°C (D version) ⁽¹⁾
Package		80-pin LQFP Package code: PLQP0080KB-A (previous code: 80P6Q-A)

Note:

1. Specify the D version if D version functions are to be used.

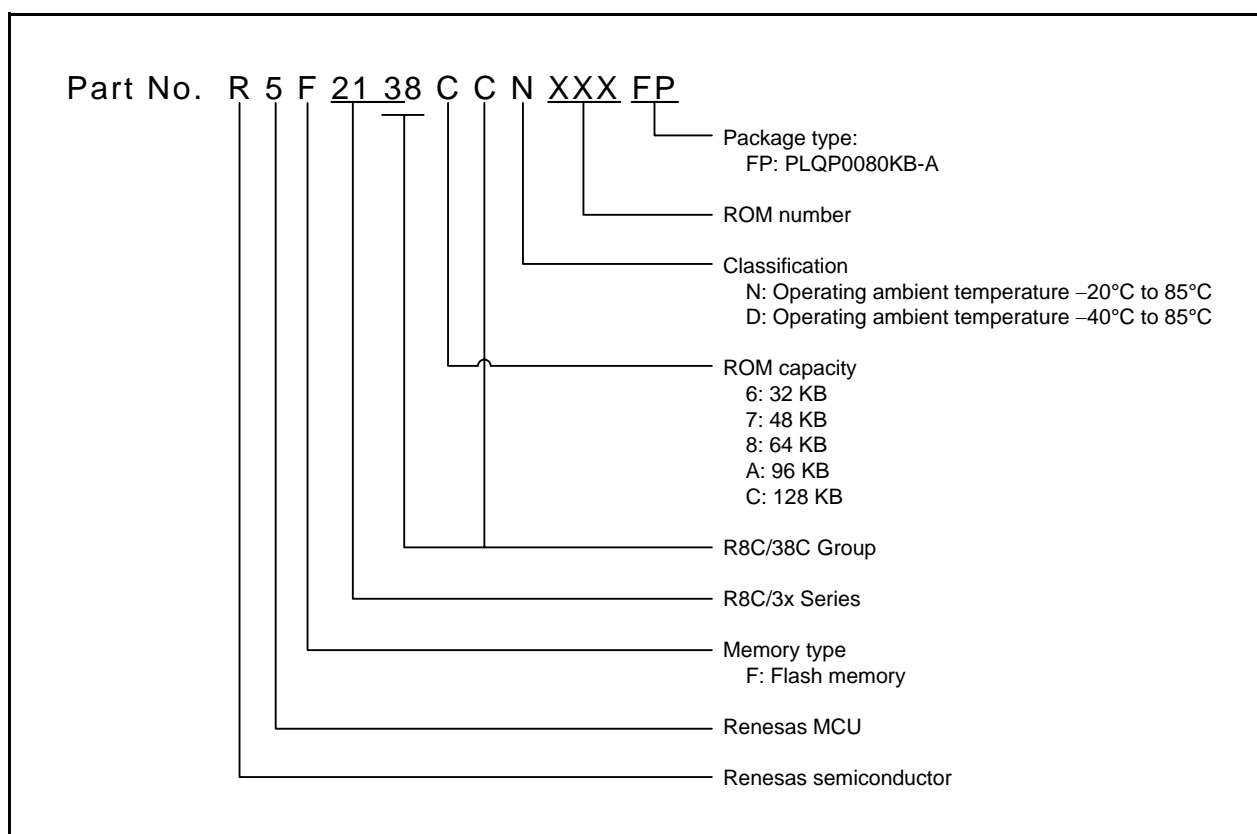


Figure 1.1 Part Number, Memory Size, and Package of R8C/38C Group

Table 1.4 Pin Name Information by Pin Number (1)

Pin Number	Control Pin	Port	I/O Pin Functions for Peripheral Modules					
			Interrupt	Timer	Serial Interface	SSU	I ² C bus	A/D Converter, D/A Converter, Comparator B
1		P5_6		(TRA0/TRGIOA)				
2		P5_5		(TRAIO)				
3		P3_2	($\overline{\text{INT1}}$ / $\overline{\text{INT2}}$)	(TRAIO/TRGCLKB)				
4		P3_0		(TRA0/TRGCLKA)				
5		P4_2						VREF
6	MODE							
7	(XCIN)	P4_3						
8	(XCOUT)	P4_4						
9	$\overline{\text{RESET}}$							
10	XOUT	P4_7						
11	VSS/AVSS							
12	XIN	P4_6						
13	VCC/AVCC							
14		P5_4		(TRCIOD)				
15		P5_3		(TRCIOC)				
16		P5_2		(TRCIOB)				
17		P5_1		(TRCIOA/TRCTRG)				
18		P5_0		(TRCCLK)				
19		P3_7		TRA0	(TXD2/SDA2/ RXD2/SCL2)	SSO	SDA	
20		P3_5		(TRCIOD)	(CLK2)	SSCK	SCL	
21		P3_4		(TRCIOC)	(TXD2/SDA2/ RXD2/SCL2)	SSI		IVREF3
22		P3_3	$\overline{\text{INT3}}$	(TRCCLK)	(CTS2/RTS2)	$\overline{\text{SCS}}$		IVCMP3
23		P2_7		(TRDIOD1)				
24		P2_6		(TRDIOC1)				
25		P2_5		(TRDIOB1)				
26		P2_4		(TRDIOA1)				
27		P2_3		(TRDIOD0)				
28		P2_2		(TRCIOD/TRDIOB0)				
29		P2_1		(TRCIOC/TRDIOC0)				
30		P2_0	($\overline{\text{INT1}}$)	(TRCIOB/TRDIOA0/ TRDCLK)				
31		P9_3						
32		P9_2						
33		P9_1						
34		P9_0						
35		P3_6	($\overline{\text{INT1}}$)					
36		P3_1		(TRBO)				
37		P8_7						
38		P8_6						
39		P8_5		(TRFO12)				
40		P8_4		(TRFO11)				

Note:

1. Can be assigned to the pin in parentheses by a program.

2. Central Processing Unit (CPU)

Figure 2.1 shows the CPU Registers. The CPU contains 13 registers. R0, R1, R2, R3, A0, A1, and FB configure a register bank. There are two sets of register bank.

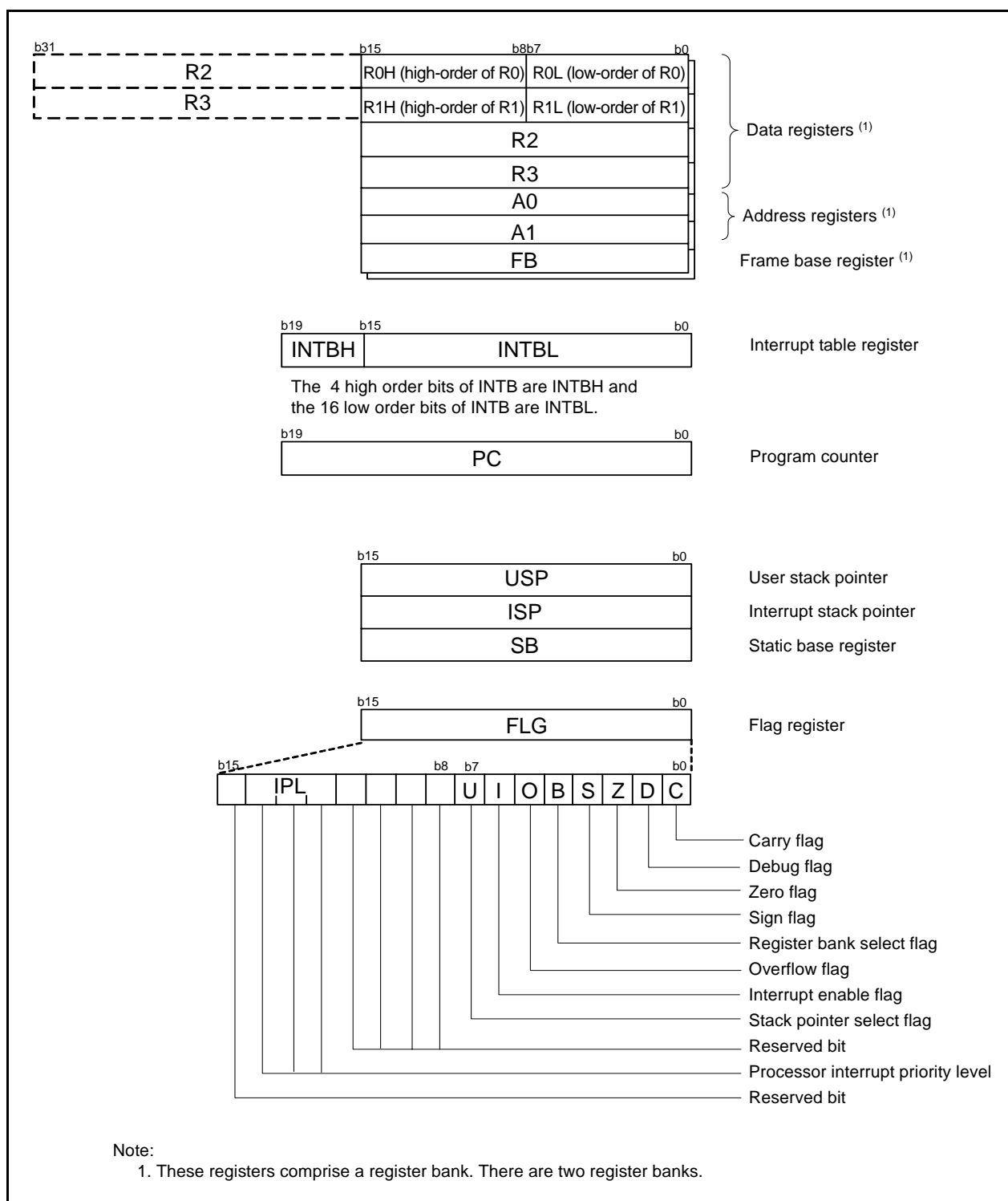


Figure 2.1 CPU Registers

3. Memory

3.1 R8C/38C Group

Figure 3.1 is a Memory Map of R8C/38C Group. The R8C/38C Group has a 1-Mbyte address space from addresses 00000h to FFFFFh. The internal ROM (program ROM) is allocated lower addresses, beginning with address 0FFFFh. For example, a 64-Kbyte internal ROM area is allocated addresses 04000h to 13FFFh.

The fixed interrupt vector table is allocated addresses 0FFDCh to 0FFFFh. The starting address of each interrupt routine is stored here.

The internal ROM (data flash) is allocated addresses 03000h to 03FFFh.

The internal RAM is allocated higher addresses, beginning with address 00400h. For example, a 6-Kbyte internal RAM area is allocated addresses 00400h to 01BFFh. The internal RAM is used not only for data storage but also as a stack area when a subroutine is called or when an interrupt request is acknowledged.

Special function registers (SFRs) are allocated addresses 00000h to 002FFh and 02C00h to 02FFFh (the SFR areas for the DTC and other modules). Peripheral function control registers are allocated here. All unallocated spaces within the SFRs are reserved and cannot be accessed by users.

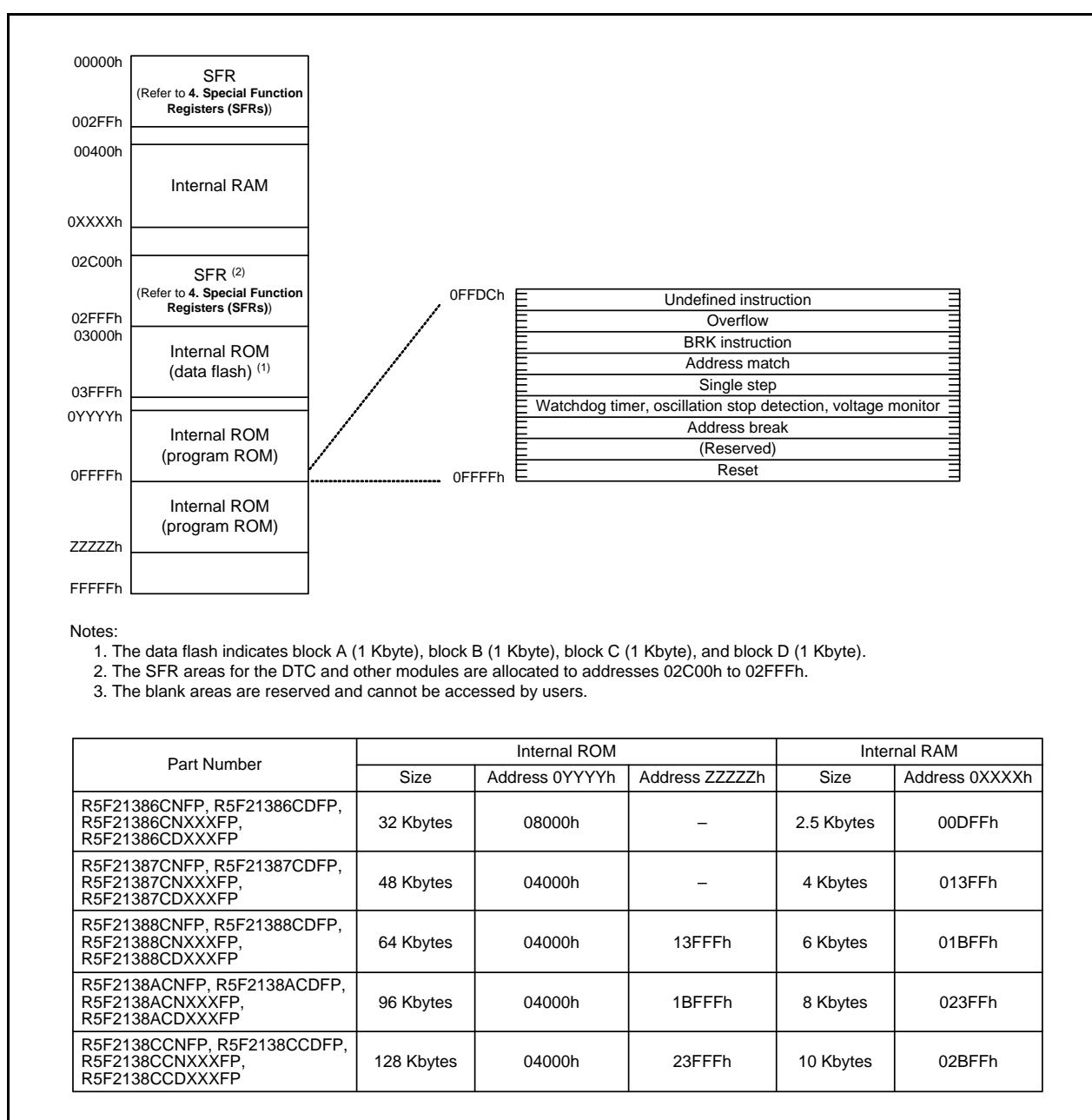


Figure 3.1 Memory Map of R8C/38C Group

Table 4.3 SFR Information (3) (1)

Address	Register	Symbol	After Reset
0080h	DTC Activation Control Register	DTCTL	00h
0081h			
0082h			
0083h			
0084h			
0085h			
0086h			
0087h			
0088h	DTC Activation Enable Register 0	DTCEN0	00h
0089h	DTC Activation Enable Register 1	DTCEN1	00h
008Ah	DTC Activation Enable Register 2	DTCEN2	00h
008Bh	DTC Activation Enable Register 3	DTCEN3	00h
008Ch	DTC Activation Enable Register 4	DTCEN4	00h
008Dh	DTC Activation Enable Register 5	DTCEN5	00h
008Eh	DTC Activation Enable Register 6	DTCEN6	00h
008Fh			
0090h	Timer RF Register	TRF	00h
0091h			00h
0092h			
0093h			
0094h			
0095h			
0096h			
0097h			
0098h			
0099h			
009Ah	Timer RF Control Register 0	TRFCR0	00h
009Bh	Timer RF Control Register 1	TRFCR1	00h
009Ch	Capture and Compare 0 Register	TRFM0	00h
009Dh			00h
009Eh	Compare 1 Register	TRFM1	FFh
009Fh			FFh
00A0h	UART0 Transmit/Receive Mode Register	U0MR	00h
00A1h	UART0 Bit Rate Register	U0BRG	XXh
00A2h	UART0 Transmit Buffer Register	U0TB	XXh
00A3h			XXh
00A4h	UART0 Transmit/Receive Control Register 0	U0C0	00001000b
00A5h	UART0 Transmit/Receive Control Register 1	U0C1	00000010b
00A6h	UART0 Receive Buffer Register	U0RB	XXh
00A7h			XXh
00A8h	UART2 Transmit/Receive Mode Register	U2MR	00h
00A9h	UART2 Bit Rate Register	U2BRG	XXh
00AAh	UART2 Transmit Buffer Register	U2TB	XXh
00ABh			XXh
00ACh	UART2 Transmit/Receive Control Register 0	U2C0	00001000b
00ADh	UART2 Transmit/Receive Control Register 1	U2C1	00000010b
00AEh	UART2 Receive Buffer Register	U2RB	XXh
00AFh			XXh
00B0h	UART2 Digital Filter Function Select Register	URXDF	00h
00B1h			
00B2h			
00B3h			
00B4h			
00B5h			
00B6h			
00B7h			
00B8h			
00B9h			
00BAh			
00BBh	UART2 Special Mode Register 5	U2SMR5	00h
00BCh	UART2 Special Mode Register 4	U2SMR4	00h
00BDh	UART2 Special Mode Register 3	U2SMR3	000X0X0Xb
00BEh	UART2 Special Mode Register 2	U2SMR2	X0000000b
00BFh	UART2 Special Mode Register	U2SMR	X0000000b

X: Undefined

Note:

1. The blank areas are reserved and cannot be accessed by users.

Table 4.7 SFR Information (7) ⁽¹⁾

Address	Register	Symbol	After Reset
0180h	Timer RA Pin Select Register	TRASR	00h
0181h	Timer RB/RC Pin Select Register	TRBRCSR	00h
0182h	Timer RC Pin Select Register 0	TRCPSR0	00h
0183h	Timer RC Pin Select Register 1	TRCPSR1	00h
0184h	Timer RD Pin Select Register 0	TRDPSR0	00h
0185h	Timer RD Pin Select Register 1	TRDPSR1	00h
0186h	Timer Pin Select Register	TIMSR	00h
0187h	Timer RF Output Control Register	TRFOUT	00h
0188h	UART0 Pin Select Register	U0SR	00h
0189h	UART1 Pin Select Register	U1SR	00h
018Ah	UART2 Pin Select Register 0	U2SR0	00h
018Bh	UART2 Pin Select Register 1	U2SR1	00h
018Ch	SSU/IIC Pin Select Register	SSUIICSR	00h
018Dh			
018Eh	INT Interrupt Input Pin Select Register	INTSR	00h
018Fh	I/O Function Pin Select Register	PINSR	00h
0190h			
0191h			
0192h			
0193h	SS Bit Counter Register	SSBR	11111000b
0194h	SS Transmit Data Register L / IIC bus Transmit Data Register ⁽²⁾	SSTDR / ICDRT	FFh
0195h	SS Transmit Data Register H ⁽²⁾	SSTDRH	FFh
0196h	SS Receive Data Register L / IIC bus Receive Data Register ⁽²⁾	SSRDR / ICDRR	FFh
0197h	SS Receive Data Register H ⁽²⁾	SSRDRH	FFh
0198h	SS Control Register H / IIC bus Control Register 1 ⁽²⁾	SSCRH / ICCR1	00h
0199h	SS Control Register L / IIC bus Control Register 2 ⁽²⁾	SSCRL / ICCR2	01111101b
019Ah	SS Mode Register / IIC bus Mode Register ⁽²⁾	SSMR / ICMR	00010000b / 00011000b
019Bh	SS Enable Register / IIC bus Interrupt Enable Register ⁽²⁾	SSER / ICIER	00h
019Ch	SS Status Register / IIC bus Status Register ⁽²⁾	SSSR / ICSR	00h / 0000X000b
019Dh	SS Mode Register 2 / Slave Address Register ⁽²⁾	SSMR2 / SAR	00h
019Eh			
019Fh			
01A0h			
01A1h			
01A2h			
01A3h			
01A4h			
01A5h			
01A6h			
01A7h			
01A8h			
01A9h			
01AAh			
01ABh			
01ACh			
01ADh			
01AEh			
01AFh			
01B0h			
01B1h			
01B2h	Flash Memory Status Register	FST	10000X00b
01B3h			
01B4h	Flash Memory Control Register 0	FMR0	00h
01B5h	Flash Memory Control Register 1	FMR1	00h
01B6h	Flash Memory Control Register 2	FMR2	00h
01B7h			
01B8h			
01B9h			
01BAh			
01BBh			
01BCh			
01BDh			
01BEh			
01BFh			

X: Undefined

Notes:

1. The blank areas are reserved and cannot be accessed by users.
2. Selectable by the IICSEL bit in the SSUIICSR register.

Table 4.8 SFR Information (8) (1)

Address	Register	Symbol	After Reset
01C0h	Address Match Interrupt Register 0	RMAD0	XXh
01C1h			XXh
01C2h			0000XXXXb
01C3h	Address Match Interrupt Enable Register 0	AIER0	00h
01C4h	Address Match Interrupt Register 1	RMAD1	XXh
01C5h			XXh
01C6h			0000XXXXb
01C7h	Address Match Interrupt Enable Register 1	AIER1	00h
01C8h			
01C9h			
01CAh			
01CBh			
01CCh			
01CDh			
01CEh			
01CFh			
01D0h			
01D1h			
01D2h			
01D3h			
01D4h			
01D5h			
01D6h			
01D7h			
01D8h			
01D9h			
01DAh			
01DBh			
01DCh			
01DDh			
01DEh			
01DFh			
01E0h	Pull-Up Control Register 0	PUR0	00h
01E1h	Pull-Up Control Register 1	PUR1	00h
01E2h	Pull-Up Control Register 2	PUR2	00h
01E3h			
01E4h			
01E5h			
01E6h			
01E7h			
01E8h			
01E9h			
01EAh			
01EBh			
01ECh			
01EDh			
01EEh			
01EFh			
01F0h	Port P1 Drive Capacity Control Register	P1DRR	00h
01F1h	Port P2 Drive Capacity Control Register	P2DRR	00h
01F2h	Drive Capacity Control Register 0	DRR0	00h
01F3h	Drive Capacity Control Register 1	DRR1	00h
01F4h	Drive Capacity Control Register 2	DRR2	00h
01F5h	Input Threshold Control Register 0	VLT0	00h
01F6h	Input Threshold Control Register 1	VLT1	00h
01F7h	Input Threshold Control Register 2	VLT2	00h
01F8h	Comparator B Control Register 0	INTCMP	00h
01F9h			
01FAh	External Input Enable Register 0	INTEN	00h
01FBh	External Input Enable Register 1	INTEN1	00h
01FCh	INT Input Filter Select Register 0	INTF	00h
01FDh	INT Input Filter Select Register 1	INTF1	00h
01FEh	Key Input Enable Register 0	KIEN	00h
01FFh			

X: Undefined

Note:

1. The blank areas are reserved and cannot be accessed by users.

5. Electrical Characteristics

Table 5.1 Absolute Maximum Ratings

Symbol	Parameter	Condition	Rated Value	Unit
V _{CC} /AV _{CC}	Supply voltage		–0.3 to 6.5	V
V _I	Input voltage		–0.3 to V _{CC} + 0.3	V
V _O	Output voltage		–0.3 to V _{CC} + 0.3	V
P _d	Power dissipation	–40°C ≤ T _{opr} ≤ 85°C	500	mW
T _{opr}	Operating ambient temperature		–20 to 85 (N version)/ –40 to 85 (D version)	°C
T _{stg}	Storage temperature		–65 to 150	°C

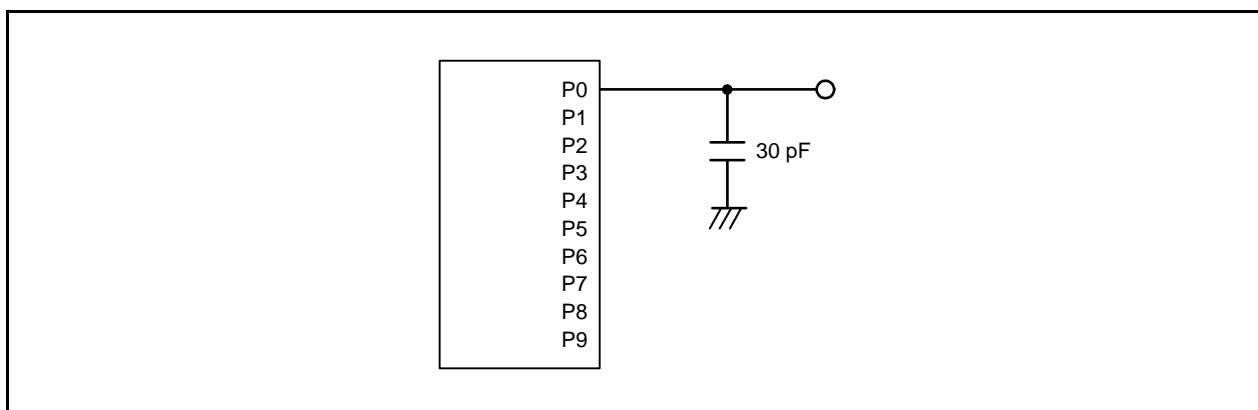


Figure 5.1 Ports P0 to P9 Timing Measurement Circuit

Table 5.8 Voltage Detection 0 Circuit Electrical Characteristics

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
Vdet0	Voltage detection level Vdet0_0 ⁽²⁾		1.80	1.90	2.05	V
	Voltage detection level Vdet0_1 ⁽²⁾		2.15	2.35	2.50	V
	Voltage detection level Vdet0_2 ⁽²⁾		2.70	2.85	3.05	V
	Voltage detection level Vdet0_3 ⁽²⁾		3.55	3.80	4.05	V
—	Voltage detection 0 circuit response time ⁽⁴⁾	At the falling of Vcc from 5.0 V to (Vdet0_0 – 0.1) V	—	6	150	μs
—	Voltage detection circuit self power consumption	VCA25 = 1, Vcc = 5.0 V	—	1.5	—	μA
td(E-A)	Waiting time until voltage detection circuit operation starts ⁽³⁾		—	—	100	μs

Notes:

1. The measurement condition is Vcc = 1.8 to 5.5 V and T_{opr} = –20 to 85 °C (N version)/–40 to 85 °C (D version).
2. Select the voltage detection level with bits VDSEL0 and VDSEL1 in the OFS register.
3. Necessary time until the voltage detection circuit operates when setting to 1 again after setting the VCA25 bit in the VCA2 register to 0.
4. Time until the voltage monitor 0 reset is generated after the voltage passes Vdet0.

Table 5.9 Voltage Detection 1 Circuit Electrical Characteristics

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
Vdet1	Voltage detection level Vdet1_0 ⁽²⁾	At the falling of Vcc	2.00	2.20	2.40	V
	Voltage detection level Vdet1_1 ⁽²⁾	At the falling of Vcc	2.15	2.35	2.55	V
	Voltage detection level Vdet1_2 ⁽²⁾	At the falling of Vcc	2.30	2.50	2.70	V
	Voltage detection level Vdet1_3 ⁽²⁾	At the falling of Vcc	2.45	2.65	2.85	V
	Voltage detection level Vdet1_4 ⁽²⁾	At the falling of Vcc	2.60	2.80	3.00	V
	Voltage detection level Vdet1_5 ⁽²⁾	At the falling of Vcc	2.75	2.95	3.15	V
	Voltage detection level Vdet1_6 ⁽²⁾	At the falling of Vcc	2.85	3.10	3.40	V
	Voltage detection level Vdet1_7 ⁽²⁾	At the falling of Vcc	3.00	3.25	3.55	V
	Voltage detection level Vdet1_8 ⁽²⁾	At the falling of Vcc	3.15	3.40	3.70	V
	Voltage detection level Vdet1_9 ⁽²⁾	At the falling of Vcc	3.30	3.55	3.85	V
	Voltage detection level Vdet1_A ⁽²⁾	At the falling of Vcc	3.45	3.70	4.00	V
	Voltage detection level Vdet1_B ⁽²⁾	At the falling of Vcc	3.60	3.85	4.15	V
	Voltage detection level Vdet1_C ⁽²⁾	At the falling of Vcc	3.75	4.00	4.30	V
	Voltage detection level Vdet1_D ⁽²⁾	At the falling of Vcc	3.90	4.15	4.45	V
	Voltage detection level Vdet1_E ⁽²⁾	At the falling of Vcc	4.05	4.30	4.60	V
	Voltage detection level Vdet1_F ⁽²⁾	At the falling of Vcc	4.20	4.45	4.75	V
—	Hysteresis width at the rising of Vcc in voltage detection 1 circuit	Vdet1_0 to Vdet1_5 selected	—	0.07	—	V
		Vdet1_6 to Vdet1_F selected	—	0.10	—	V
—	Voltage detection 1 circuit response time ⁽³⁾	At the falling of Vcc from 5.0 V to (Vdet1_0 – 0.1) V	—	60	150	μs
—	Voltage detection circuit self power consumption	VCA26 = 1, Vcc = 5.0 V	—	1.7	—	μA
td(E-A)	Waiting time until voltage detection circuit operation starts ⁽⁴⁾		—	—	100	μs

Notes:

1. The measurement condition is Vcc = 1.8 to 5.5 V and T_{opr} = –20 to 85 °C (N version)/–40 to 85 °C (D version).
2. Select the voltage detection level with bits VD1S0 to VD1S3 in the VD1LS register.
3. Time until the voltage monitor 1 interrupt request is generated after the voltage passes Vdet1.
4. Necessary time until the voltage detection circuit operates when setting to 1 again after setting the VCA26 bit in the VCA2 register to 0.

Table 5.12 High-speed On-Chip Oscillator Circuit Electrical Characteristics

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
—	High-speed on-chip oscillator frequency after reset	$V_{CC} = 1.8 \text{ V to } 5.5 \text{ V}$ $-20 \text{ }^{\circ}\text{C} \leq T_{opr} \leq 85 \text{ }^{\circ}\text{C}$	38.4	40	41.6	MHz
		$V_{CC} = 1.8 \text{ V to } 5.5 \text{ V}$ $-40 \text{ }^{\circ}\text{C} \leq T_{opr} \leq 85 \text{ }^{\circ}\text{C}$	38.0	40	42.0	MHz
	High-speed on-chip oscillator frequency when the FRA4 register correction value is written into the FRA1 register and the FRA5 register correction value into the FRA3 register ⁽²⁾	$V_{CC} = 1.8 \text{ V to } 5.5 \text{ V}$ $-20 \text{ }^{\circ}\text{C} \leq T_{opr} \leq 85 \text{ }^{\circ}\text{C}$	35.389	36.864	38.338	MHz
		$V_{CC} = 1.8 \text{ V to } 5.5 \text{ V}$ $-40 \text{ }^{\circ}\text{C} \leq T_{opr} \leq 85 \text{ }^{\circ}\text{C}$	35.020	36.864	38.707	MHz
	High-speed on-chip oscillator frequency when the FRA6 register correction value is written into the FRA1 register and the FRA7 register correction value into the FRA3 register	$V_{CC} = 1.8 \text{ V to } 5.5 \text{ V}$ $-20 \text{ }^{\circ}\text{C} \leq T_{opr} \leq 85 \text{ }^{\circ}\text{C}$	30.72	32	33.28	MHz
		$V_{CC} = 1.8 \text{ V to } 5.5 \text{ V}$ $-40 \text{ }^{\circ}\text{C} \leq T_{opr} \leq 85 \text{ }^{\circ}\text{C}$	30.40	32	33.60	MHz
—	Oscillation stability time	$V_{CC} = 5.0 \text{ V}$, $T_{opr} = 25 \text{ }^{\circ}\text{C}$	—	0.5	3	ms
—	Self power consumption at oscillation	$V_{CC} = 5.0 \text{ V}$, $T_{opr} = 25 \text{ }^{\circ}\text{C}$	—	400	—	μA

Notes:

1. $V_{CC} = 1.8$ to 5.5 V and $T_{opr} = -20$ to $85 \text{ }^{\circ}\text{C}$ (N version)/ -40 to $85 \text{ }^{\circ}\text{C}$ (D version), unless otherwise specified.
2. This enables the setting errors of bit rates such as 9600 bps and 38400 bps to be 0% when the serial interface is used in UART mode.

Table 5.13 Low-speed On-Chip Oscillator Circuit Electrical Characteristics

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
fOCO-S	Low-speed on-chip oscillator frequency		60	125	250	kHz
—	Oscillation stability time	$V_{CC} = 5.0 \text{ V}$, $T_{opr} = 25 \text{ }^{\circ}\text{C}$	—	30	100	μs
—	Self power consumption at oscillation	$V_{CC} = 5.0 \text{ V}$, $T_{opr} = 25 \text{ }^{\circ}\text{C}$	—	2	—	μA

Note:

1. $V_{CC} = 1.8$ to 5.5 V and $T_{opr} = -20$ to $85 \text{ }^{\circ}\text{C}$ (N version)/ -40 to $85 \text{ }^{\circ}\text{C}$ (D version), unless otherwise specified.

Table 5.14 Power Supply Circuit Timing Characteristics

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
t _{d(P-R)}	Time for internal power supply stabilization during power-on ⁽²⁾		—	—	2,000	μs

Notes:

1. The measurement condition is $V_{CC} = 1.8$ to 5.5 V and $T_{opr} = 25 \text{ }^{\circ}\text{C}$.
2. Waiting time until the internal power supply generation circuit stabilizes during power-on.

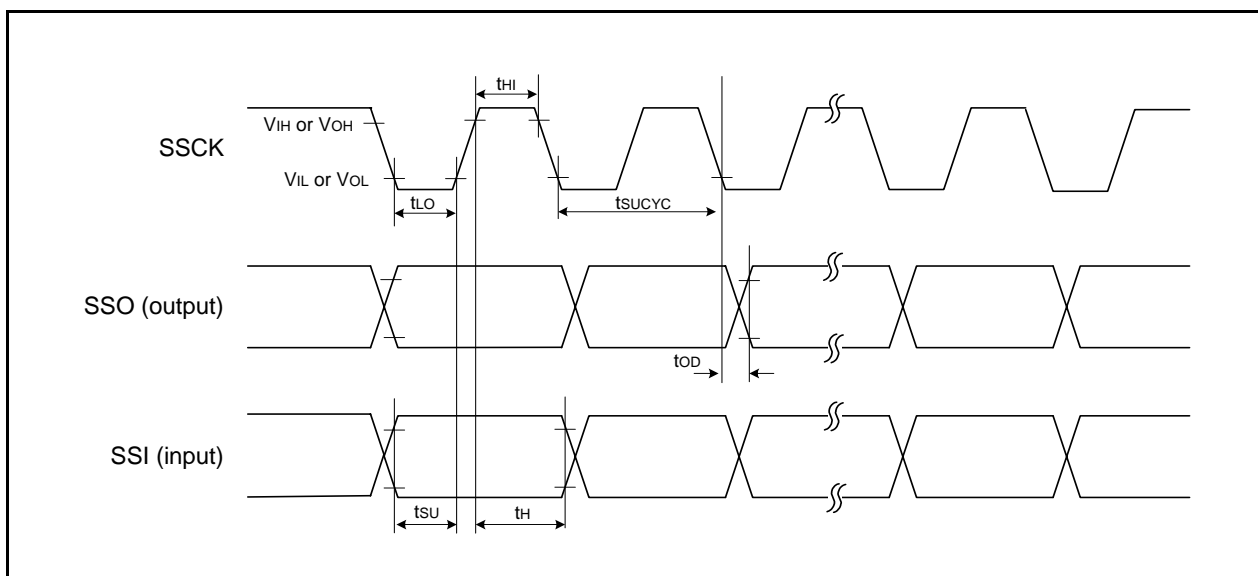


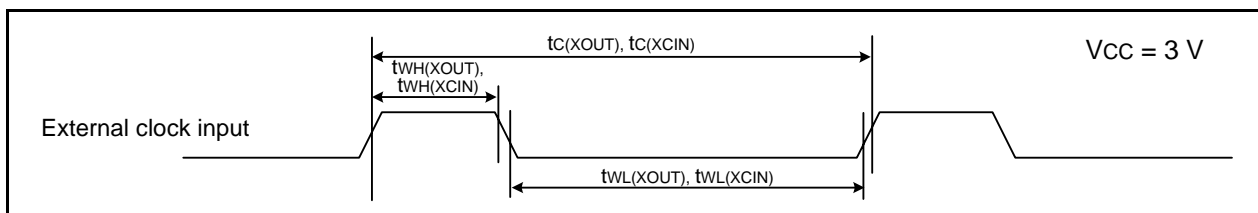
Figure 5.6 I/O Timing of Synchronous Serial Communication Unit (SSU) (Clock Synchronous Communication Mode)

Table 5.25 Electrical Characteristics (4) [$2.7\text{ V} \leq V_{CC} \leq 3.3\text{ V}$]
($T_{opr} = -20\text{ to }85\text{ }^{\circ}\text{C}$ (N version)/ $-40\text{ to }85\text{ }^{\circ}\text{C}$ (D version), unless otherwise specified.)

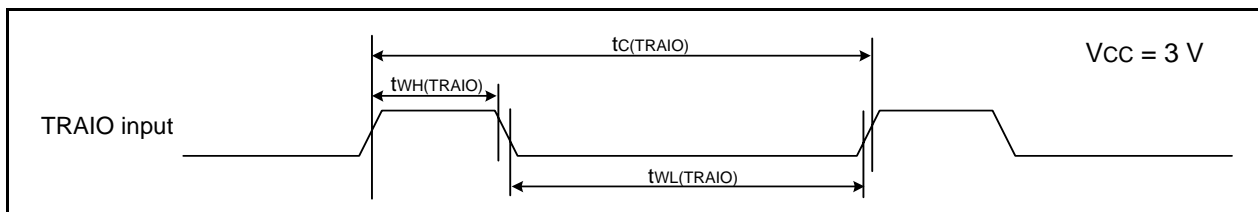
Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
I _{CC}	Power supply current ($V_{CC} = 2.7\text{ to }3.3\text{ V}$) Single-chip mode, output pins are open, other pins are V _{SS}	High-speed clock mode	—	3.5	10	mA
		High-speed on-chip oscillator mode	—	1.5	7.5	mA
		High-speed on-chip oscillator mode	—	7.0	15	mA
		Low-speed on-chip oscillator mode	—	90	390	μA
		Low-speed clock mode	—	80	400	μA
		Wait mode	—	15	90	μA
		Stop mode	—	2.0	5.0	μA

Timing requirements (Unless Otherwise Specified: $V_{CC} = 3\text{ V}$, $V_{SS} = 0\text{ V}$, $T_{opr} = 25\text{ }^{\circ}\text{C}$)**Table 5.26 External Clock Input (XOUT, XCIN)**

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_c(\text{XOUT})$	XOUT input cycle time	50	—	ns
$t_{WH}(\text{XOUT})$	XOUT input "H" width	24	—	ns
$t_{WL}(\text{XOUT})$	XOUT input "L" width	24	—	ns
$t_c(\text{XCIN})$	XCIN input cycle time	14	—	μs
$t_{WH}(\text{XCIN})$	XCIN input "H" width	7	—	μs
$t_{WL}(\text{XCIN})$	XCIN input "L" width	7	—	μs

**Figure 5.13 External Clock Input Timing Diagram when $V_{CC} = 3\text{ V}$** **Table 5.27 TRAIO Input**

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_c(\text{TRAIO})$	TRAIO input cycle time	300	—	ns
$t_{WH}(\text{TRAIO})$	TRAIO input "H" width	120	—	ns
$t_{WL}(\text{TRAIO})$	TRAIO input "L" width	120	—	ns

**Figure 5.14 TRAIO Input Timing Diagram when $V_{CC} = 3\text{ V}$** **Table 5.28 TRFI Input**

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_c(\text{TRFI})$	TRFI input cycle time	1200 (1)	—	ns
$t_{WH}(\text{TRFI})$	TRFI input "H" width	600 (2)	—	ns
$t_{WL}(\text{TRFI})$	TRFI input "L" width	600 (2)	—	ns

Notes:

1. When using timer RF input capture mode, adjust the cycle time to $(1/\text{timer RF count source frequency} \times 3)$ or above.
2. When using timer RF input capture mode, adjust the pulse width to $(1/\text{timer RF count source frequency} \times 1.5)$ or above.

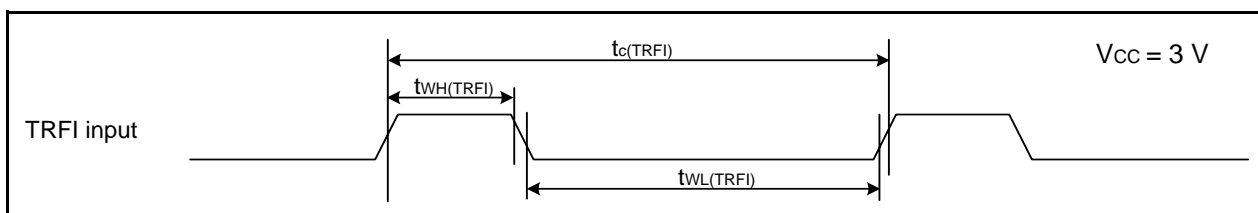
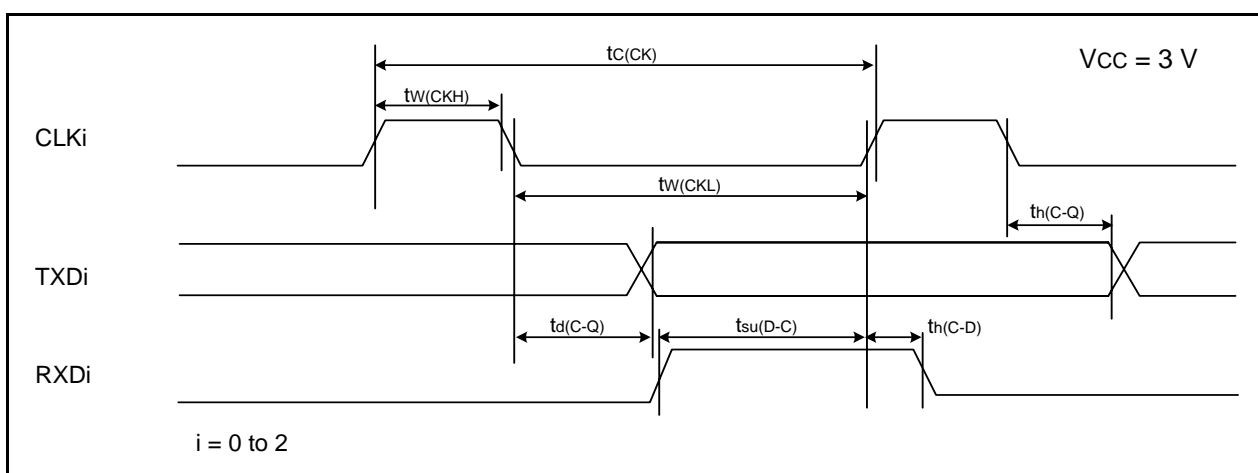
**Figure 5.15 TRFI Input Timing Diagram when $V_{CC} = 3\text{ V}$**

Table 5.29 Serial Interface

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_c(\text{CK})$	CLKi input cycle time	300	—	ns
$t_w(\text{CKH})$	CLKi input "H" width	150	—	ns
$t_w(\text{CKL})$	CLKi Input "L" width	150	—	ns
$t_d(\text{C-Q})$	TXDi output delay time	—	80	ns
$t_h(\text{C-Q})$	TXDi hold time	0	—	ns
$t_{su}(\text{D-C})$	RXDi input setup time	70	—	ns
$t_h(\text{C-D})$	RXDi input hold time	90	—	ns

 $i = 0 \text{ to } 2$ **Figure 5.16 Serial Interface Timing Diagram when Vcc = 3 V****Table 5.30 External Interrupt $\overline{\text{INT}}i$ ($i = 0 \text{ to } 4$) Input, Key Input Interrupt $\overline{\text{K}}i$ ($i = 0 \text{ to } 3$)**

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_w(\text{INH})$	$\overline{\text{INT}}i$ input "H" width, $\overline{\text{K}}i$ input "H" width	380 (1)	—	ns
$t_w(\text{INL})$	$\overline{\text{INT}}i$ input "L" width, $\overline{\text{K}}i$ input "L" width	380 (2)	—	ns

Notes:

1. When selecting the digital filter by the $\overline{\text{INT}}i$ input filter select bit, use an $\overline{\text{INT}}i$ input HIGH width of either (1/digital filter clock frequency $\times 3$) or the minimum value of standard, whichever is greater.
2. When selecting the digital filter by the $\overline{\text{INT}}i$ input filter select bit, use an $\overline{\text{INT}}i$ input LOW width of either (1/digital filter clock frequency $\times 3$) or the minimum value of standard, whichever is greater.

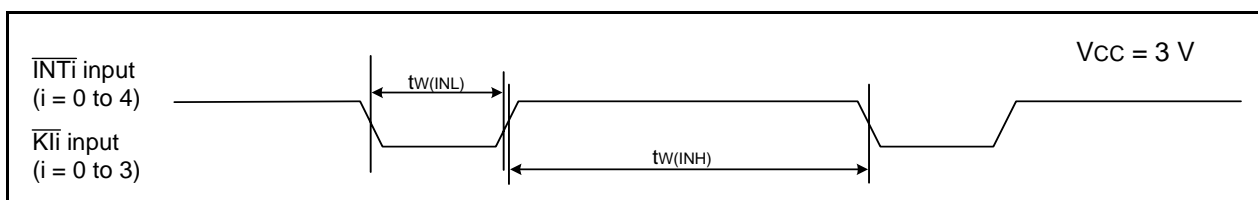
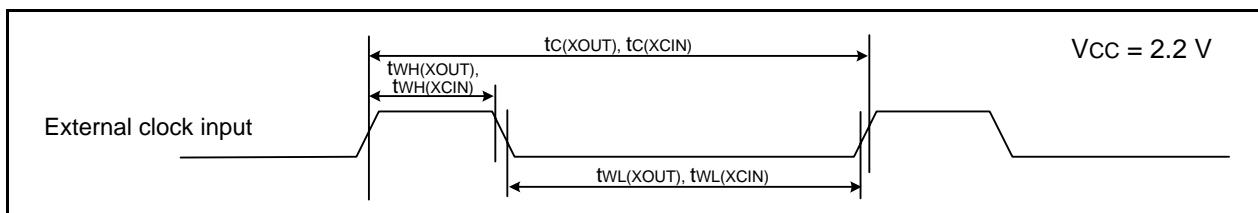
**Figure 5.17 Input Timing Diagram for External Interrupt $\overline{\text{INT}}i$ and Key Input Interrupt $\overline{\text{K}}i$ when Vcc = 3 V**

Table 5.32 Electrical Characteristics (6) [$1.8\text{ V} \leq V_{CC} < 2.7\text{ V}$]
($T_{opr} = -20\text{ to }85\text{ }^{\circ}\text{C}$ (N version)/ $-40\text{ to }85\text{ }^{\circ}\text{C}$ (D version), unless otherwise specified.)

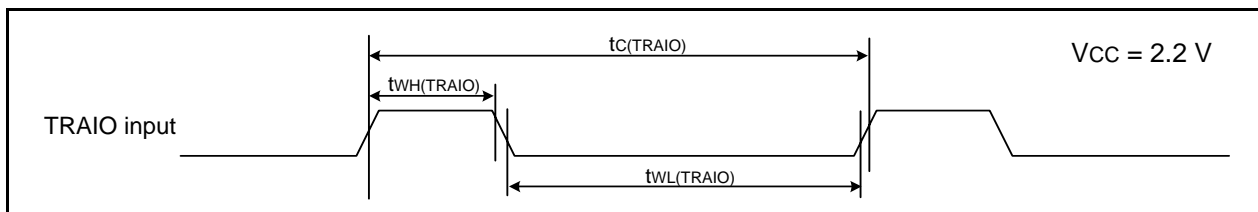
Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
I _{CC}	Power supply current ($V_{CC} = 1.8\text{ to }2.7\text{ V}$) Single-chip mode, output pins are open, other pins are V _{SS}	High-speed clock mode	—	2.2	—	mA
		XIN = 5 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	—	0.8	—	mA
		XIN = 5 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	—	1.7	—	mA
		High-speed on-chip oscillator mode	—	2.5	10	mA
		XIN clock off High-speed on-chip oscillator on fOCO-F = 5 MHz Low-speed on-chip oscillator on = 125 kHz No division	—	1	—	mA
		XIN clock off High-speed on-chip oscillator on fOCO-F = 5 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8	—	1	—	mA
		XIN clock off High-speed on-chip oscillator on fOCO-F = 4 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-16, MSTIIC = MSTTRD = MSTTRC = 1	—	1	—	mA
		Low-speed on-chip oscillator mode	—	90	300	μA
		Low-speed clock mode	—	80	350	μA
		XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz No division FMR27 = 1, VCA20 = 0	—	40	—	μA
		XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz No division Program operation on RAM Flash memory off, FMSTP = 1, VCA20 = 0	—	40	—	μA
		Wait mode	—	15	90	μA
		XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock operation VCA27 = VCA26 = VCA25 = 0, VCA20 = 1	—	4	80	μA
		XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock off VCA27 = VCA26 = VCA25 = 0, VCA20 = 1	—	3.5	—	μA
		XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz (peripheral clock off) While a WAIT instruction is executed VCA27 = VCA26 = VCA25 = 0, VCA20 = 1	—	3.5	—	μA
		Stop mode	—	2.0	5	μA
		XIN clock off, $T_{opr} = 25\text{ }^{\circ}\text{C}$ High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	—	15	—	μA
		XIN clock off, $T_{opr} = 85\text{ }^{\circ}\text{C}$ High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	—	15	—	μA

Timing requirements (Unless Otherwise Specified: $V_{CC} = 2.2\text{ V}$, $V_{SS} = 0\text{ V}$, $T_{opr} = 25\text{ }^{\circ}\text{C}$)**Table 5.33 External Clock Input (XOUT, XCIN)**

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_c(\text{XOUT})$	XOUT input cycle time	200	—	ns
$t_{WH}(\text{XOUT})$	XOUT input "H" width	90	—	ns
$t_{WL}(\text{XOUT})$	XOUT input "L" width	90	—	ns
$t_c(\text{XCIN})$	XCIN input cycle time	14	—	μs
$t_{WH}(\text{XCIN})$	XCIN input "H" width	7	—	μs
$t_{WL}(\text{XCIN})$	XCIN input "L" width	7	—	μs

**Figure 5.18 External Clock Input Timing Diagram when $V_{CC} = 2.2\text{ V}$** **Table 5.34 TRAIO Input**

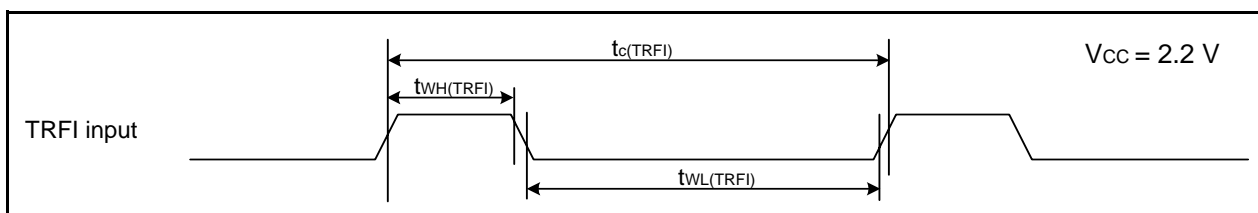
Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_c(\text{TRAIO})$	TRAIO input cycle time	500	—	ns
$t_{WH}(\text{TRAIO})$	TRAIO input "H" width	200	—	ns
$t_{WL}(\text{TRAIO})$	TRAIO input "L" width	200	—	ns

**Figure 5.19 TRAIO Input Timing Diagram when $V_{CC} = 2.2\text{ V}$** **Table 5.35 TRFI Input**

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_c(\text{TRFI})$	TRFI input cycle time	2000 (1)	—	ns
$t_{WH}(\text{TRFI})$	TRFI input "H" width	1000 (2)	—	ns
$t_{WL}(\text{TRFI})$	TRFI input "L" width	1000 (2)	—	ns

Notes:

1. When using timer RF input capture mode, adjust the cycle time to $(1/\text{timer RF count source frequency} \times 3)$ or above.
2. When using timer RF input capture mode, adjust the pulse width to $(1/\text{timer RF count source frequency} \times 1.5)$ or above.

**Figure 5.20 TRFI Input Timing Diagram when $V_{CC} = 2.2\text{ V}$**

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